

## DOCUMENT CHANGE REQUEST

1468 Originator: Geraldine Chaumont DCR number Changes required for: General Date: 2022/02/15 Date sent: 2021/10/06 Organisation: STMicroelectronics Status: IMPLEMENTED Title: Transistors High Voltage NPN, based on type 2N5551 9 Number: 5201/019 Issue: Other documents affected: Page: 14 and 17 Paragraph: 2.4.1 and 2.9.2 Original wording: No Iceo parameter listed Proposed wording: Insert Iceo parameter Justification: Based on customer request, validated by ESA people. Attachments: 5201019iss9\_dcr.pdf Modifications: N/A Approval signature: Milistan Date signed: 2022-02-15